Experimental progress towards probing the ground state of an electron-hole bilayer by low-temperature transport

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Closely spaced two-dimensional electron and hole gases are of significant interest when the layer separation approaches the excitonic Bohr radius (~10nm in GaAs). The ground state phase diagram of such a system is anticipated to be rich, including an excitonic superfluid predicted over 30 years ago [1], a BEC-BCS crossover and density modulated phases including charge density waves and Wigner crystals [2].

Experimental realisation however, has proven extremely difficult. Only recently has it been possible to design independently contacted electrically generated electron-hole bilayers (EHBLs) where exciton formation is considered likely. Devices have reached carrier densities less than 5×10^{10} cm⁻² in each layer and a separation of 10–20nm in a GaAs/AlGaAs based system [3,4]. In these EHBLs, the interlayer interaction can be stronger than the intralayer interactions.

In these devices, the interlayer interaction can be probed directly using the Coulomb drag technique. A current is passed in one layer, and momentum transferred to the other layer is detected as a voltage. Experiments have revealed that the Coulomb drag on the hole layer shows strong nonmonotonic deviations from the behaviour expected for Fermi-liquids at low temperatures [3,4]. Simultaneously, an unexpected insulating behaviour in the single-layer resistances (in a highly "metallic" regime with $\rho << h/e^2$) also appears in both layers despite electron mobilities of above $\sim 10^6 \text{ cm}^2 \text{V}^{-1} \text{s}^{-1}$ and hole mobilities above $\sim 10^5 \text{ cm}^2 \text{V}^{-1} \text{s}^{-1}$ [5]. Experimental data also indicates that the point of equal densities (*n=p*) is not special.

[1] Yu.E. Lozovik and V.I. Yudson, Sov. Phys. JETP 44, 389 (1976)

[2] L. Liu et al., Phys. Rev. B 53, 7923 (1996)

[3] A.F. Croxall et al., Phys. Rev. Lett. 101, 246801 (2008)

[4] J.A. Seamons et al., Phys. Rev. Lett. 102, 026804 (2009)

[5] A.F. Croxall et al., Phys. Rev. B. 80, 125323 (2009)